

# Weizhen Wang

## List of Publications by Year in descending order

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2682572

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#	ARTICLE	IF	CITATIONS
1	Growth conditions of metal-catalyzed, laterally grown Ge films on Si. Thin Solid Films, 2020, 709, 138133.	1.8	1
2	Transmission electron microscopy dislocation study of Ge-on-Si films supporting a new lattice-mismatch relaxation mechanism. Journal of Applied Physics, 2020, 127, 075301.	2.5	2
3	Effects of Au catalyst geometry on Ge films grown laterally on Si using the vapor-liquid-solid mechanism. Journal Physics D: Applied Physics, 2019, 52, 255101.	2.8	5
4	New Relaxation Mechanism Enabling High-Quality, Laterally Grown Ge on Si. Crystal Growth and Design, 2019, 19, 23-29.	3.0	6